

SMBus/I²C 8-Channel LED Driver

ISL97677

The ISL97677 is an SMBus/I 2 C controlled multi-channel LED driver for notebook and monitor LCD backlight applications with PWM dimming and fault reporting functions. The ISL97677 is capable of driving typically 96 pieces of 3.4V/50mA LEDs. The ISL97677 has multiple channels of voltage controlled current sources with typical currents matching to $\pm 0.7\%$, which compensate for the non-uniformity effect of forward voltages variance in the LED strings. To minimize the voltage headroom and power loss in the typical multi-string operation, the ISL97677 features dynamic headroom control that monitors the highest LED forward voltage string and uses its feedback signal for output regulation.

The ISL97677 can operate in multiple modes of operations. It can be controlled by SMBus/ I^2C communications and an external PWM dimming signal with currents matching of $\pm 1\%$ across all ranges.

The ISL97677 features extensive protection functions that include string open and short circuit detections, OVP, and OTP. The fault conditions will be recorded in the Fault/Status register. There are selectable short-circuit thresholds and the switching frequency can be programmed between 500kHz and 1.5MHz.

ISL97677 is available in the 32 Leads QFN 5mmx5mm and operate from -40°C to +85°C with input voltage ranges from 4.75V to 26V.

Features

- 8 Channels
- 4.75V ~ 26V Input
- 45V Maximum Output
- Drive Typically 96 LEDs (3.4V/50mA each)
- · Dimming Controls
 - SMBus/I²C 8-Bit PWM Dimming
 - SMBus and External PWM DPST Dimming Control
 - External PWM Dimming with or without SMBus/I²C
 - PWM Dimming range from 0.4% to 100%
- Current Matching ±0.7%
- · Protections
 - String Open Circuit and Short Circuit Detections, OVP, and OTP
- · Adjustable Dimming Frequency
- · Adjustable Switching Frequency
- 32 Ld (5mmx5mm) QFN Package

Applications

- · Notebook Displays WLED or RGB LED Backlighting
- · LCD Monitor LED Backlighting

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Typical Application Circuit

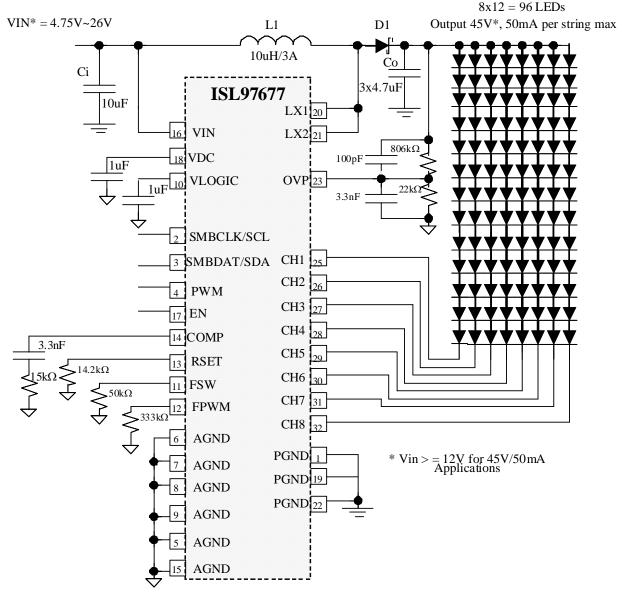


FIGURE 1. ISL97677 TYPICAL APPLICATION DIAGRAM

Block Diagram

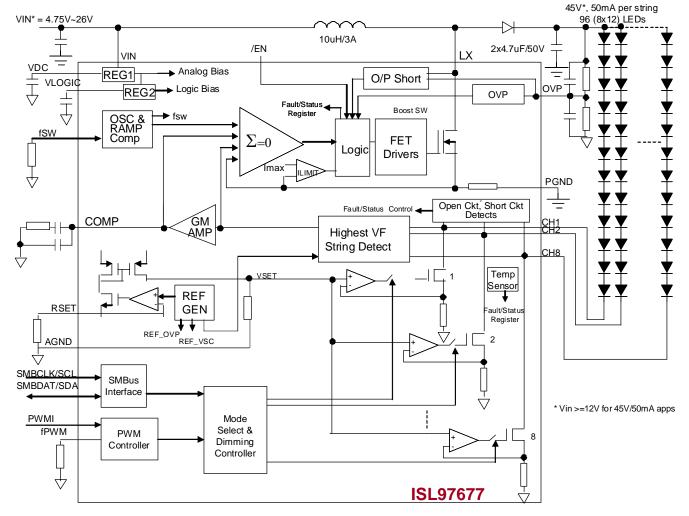


FIGURE 2. ISL97677 BLOCK DIAGRAM

Ordering Information

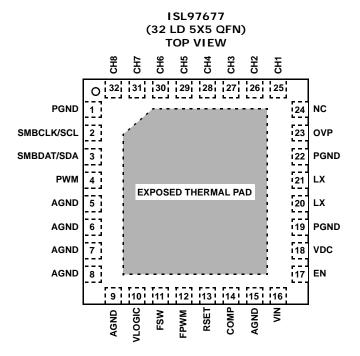
PART NUMBER	PART MARKING	PACKAGE (Pb-free)	PKG. DWG. #	
ISL97677IRZ (Notes 1, 2)	ISL9767 7IRZ	32 Ld 5x5 QFN	L32.5x5B	

NOTES:

- 1. Add "-T" or "-TK" suffix for tape and reel. Please refer to TB347 for details on reel specifications.
- 2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
- 3. For Moisture Sensitivity Level (MSL), please see device information page for <u>ISL97677</u>. For more information on MSL please see techbrief <u>TB363</u>.

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Pin Configuration



Pin Descriptions (I = Input, O = Output, S = Supply)

PIN	NAME	TYPE	DESCRIPTION	
1, 19, 22	PGND	S	Power Ground	
2	SMBCLK/SCL	I	SMBus/I ² C Serial Clock Input	
3	SMBDAT/SDA	I/O	SMBus/I ² C Serial Data Input and Output	
4	PWM	I	PWM Brightness Control	
5, 6, 7, 8, 9, 15	AGND	S	Analog Ground	
10	VLOGIC	0	Internal 2.5V Logic Bias Regulator. Need Decoupling Capacitor for Regulation	
11	FSW	I	When R_{fSW} is $100k\Omega$, f_{SW} is $500kHz$. When R_{fSW} is $33k\Omega$, f_{SW} is $1.5MHz$	
12	FPWM	I	When R_{FPWM} is $333k\Omega$, F_{PWM} is $200Hz$. When R_{FPWM} is $3.3k\Omega$, F_{PWM} is $20kHz$.	
13	RSET	I	Resistor Connection for Setting LED Current	
14	COMP	0	Boost compensation	
16	VIN	S	Main Power	
17	EN	I	Enable	
18	VDC	S	Internal 5V Analog Bias Regulator. Needs Decoupling Capacitor for Regulation	
20, 21	LX	0	Boost MOSFET Drain Terminal Switching Node	
23	OVP	I	Overvoltage Protection Input as well as Output Voltage FB Monitoring	
24	NC	I/O	No Connect	
25 ~ 32	CH1 ~ CH8	I	LED Driver PWM Dimming Monitoring	

Absolute Maximum Ratings

voltage ratings are all with respect to AGND pin
VIN
EN
VLOGIC0.3V to 2.75V
VDC0.3V to 5.75V
COMP, RSET, FPWM, FSW0.3V to min
(VDC + 0.3V, 5.75V)
SMBCLK, SMBDAT, PWM0.3V to 5.75V
CH1 - CH8, LX, OVP0.3V to 45V
PGND, AGND0.3V to +0.3V

Thermal Information

Thermal Resistance (Typical)	θ _{JA} (°C/W)	θ_{JC} (°C/W)
32 Ld QFN (Notes 4, 5)	31	3
Thermal Characterization (Typi	cal, Note 6)	PSI _{JT} (°C/W)
32 Ld QFN		. 0.2
Maximum Continuous Junction	Temperature .	+125°C
Storage Temperature	6	5°C to +150°C
Power Dissipation		
$T_A < +25^{\circ}C$		3.2W
$T_A < +70^{\circ}C$		
$T_A < +85^{\circ}C$		1.3W
$T_A < +100^{\circ}C$		
Pb-Free Reflow Profile		
http://www.intersil.com/pbfr	<u>ee/Pb-FreeReflo</u>	<u>w.asp</u>

Recommended Operating Conditions

Temperature Range -40°C to +85°C

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

- 4. θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.
- 5. For θ_{JC} , the "case temp" location is the center of the exposed metal pad on the package underside.
- 6. PSI_{JT} is the PSI junction-to-top thermal characterization parameter. If the package top temperature can be measured with this rating then the die junction temperature can be estimated more accurately than the θ_{JC} and θ_{JC} thermal resistance ratings.

Electrical Specifications

All specifications below are characterized at $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$; $V_{\text{IN}} = 12\text{V}$, /SHUT = 5V, $I_{\text{SET}} = 36\text{k}\Omega$ unless otherwise noted. **Boldface limits apply over the operating temperature range**, -40°C to +85°C.

PARAMETER	DESCRIPTION	CONDITION	MIN (Note 7)	ТҮР	MAX (Note 7)	UNIT
GENERAL						
V _{IN}	Backlight Supply Voltage		4.75		26 (Note 8)	V
IVIN_SHDN	VIN Shutdown Current	/SHUT = 0			5	μΑ
V _{OUT}	Output Voltage				45	V
V _{UVLO}	Undervoltage Lockout Threshold		2.9		3.3	V
V _{UVLO_HYS}	Undervoltage Lockout Hysteresis			300		mV
LINEAR REGULA	ATOR					
V _{DC}	5V Analog Bias Regulator	V _{IN} > 6V	4.8	5	5.1	V
V _{DC_DROP}	VDC LDO Dropout Voltage	I _{VDC} = 30mA		71	100	mV
I _{VDC}	Active Current	$/SHUT = 5V, R = 33k\Omega$		10		mA
V _{LOGIC}	2.5V Logic Bias Regulator	V _{IN} > 6V	2.3	2.4	2.5	V
V _{LOGIC_DROP}	V _{LOGIC} LDO Dropout Voltage	I _{VLOGIC} = 30mA		31	100	mV
BOOST SWITCH	ING REGULATOR			•		-
SS	Soft-Start			16		ms
SW _{ILimit}	Boost FET Current Limit	$T_A = +25^{\circ}C \text{ to } +85^{\circ}C$	3.0		4.7	Α
r _{DS(ON)}	Internal Boost Switch ON-Resistance			130		mΩ

Electrical Specifications All specifications below are characterized at $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$; $V_{1N} = 12\text{V}$, /SHUT = 5V, $I_{SET} = 36k\Omega$, unless otherwise noted. **Boldface limits apply over the operating temperature range**, -40°C to +85°C. (Continued)

PARAMETER	DESCRIPTION	CONDITION	MIN (Note 7)	ТҮР	MAX (Note 7)	UNIT
Eff_peak	Peak Efficiency	$V_{IN} = 24V$, $96LEDs$, $20mA$ each, $L = 10\mu H$ with DCR $\leq 100m\Omega$, $f_{SW} = 600kHz$, $T_A = +25^{\circ}C$		92.4		%
		$V_{IN}=12V, 96 \ LEDs,$ 20mA each, L = 10 μ H with DCR \leq 100m Ω , $f_{SW}=600kHz,$ $T_A=+25$ °C		91.5		%
		$V_{IN}=6V$, 96 LEDs, 20mA each, L = 10 μ H with DCR \leq 100m Ω , $f_{SW}=600$ kHz, $T_A=+25$ °C		81.6		%
		$V_{IN}=24V$, 80 LEDs, 40mA each, L = 10 μ H with DCR \leq 100m Ω , $f_{SW}=600$ kHz, $T_A=+25$ °C		93.4		%
		$V_{IN} = 12V$, 80 LEDs, 40mA each, L = 10 μ H with DCR \leq 100m Ω , $f_{SW} = 600kHz$, $T_A = +25$ °C		90.7		%
D _{MAX}	Boost Maximum Duty Cycle	$f_{SW} = 500kHz$	90			%
D _{MIN}	Boost Minimum Duty Cycle	$f_{SW} = 500kHz$			10	%
f _{SW}	Boost Switching Frequency	$R_{fSW} = 100k\Omega$	0.45	0.5	0.55	MHz
		$R_{fSW} = 33k\Omega$	1.35	1.5	1.65	MHz
ILX_leakage	Lx Leakage Current	VLX = 45V, /SHUT = 0V			10	μΑ
REFERENCE						
I _{MATCH}	Channel-to-Channel Current Matching	I _{LED} = 20mA	-1.1	±0.7	+1.1	%
I _{ACC}	Absolute Current Accuracy	$I_{RSET} = 36k\Omega,$ $T_A = +25^{\circ}C$	-1.5		+1.5	%
		$I_{RSET} = 36k\Omega,$ $T_{A} = -40^{\circ}C \text{ to } +80^{\circ}C$	-2		+2	%
FAULT DETECTION	ON		-			
V _{SC}	Channel Short Circuit Threshold	SMBus Register0x0F, SC[1:0] = 01	2.4		3.6	V
		SMBus Register0x0F, SC[1:0] = 10	3.3		4.6	V
		SMBus Register0x0F, SC[1:0] = 11	4.2		5.6	V
V _{temp}	Over-Temperature Threshold			150		°C
V _{temp_acc}	Over-Temperature Threshold Accuracy			5		°C
V_{OVP}	Overvoltage Limit on OVP Pin		1.18	1.22	1.24	V

Electrical Specifications

All specifications below are characterized at $T_A=-40^{\circ}C$ to $+85^{\circ}C$; $V_{IN}=12V$, /SHUT = 5V, $I_{SET}=36k\Omega$, unless otherwise noted. **Boldface limits apply over the operating** temperature range, -40°C to +85°C. (Continued)

PARAMETER	DESCRIPTION	CONDITION	MIN (Note 7)	ТҮР	MAX (Note 7)	UNIT
SMBus INTERFA	CE (SMBus Mode, 1D_EN = 0)					
V _{IL}	Logic Input Low Voltage - SMBCLK/SCL, SMBDAT/SDA				0.8	V
V _{IH}	Logic Input High Voltage - SMBCLK/SCL, SMBDAT/SDA		1.5		5.5	V
V _{OL}	SMBus Data Line Logic Low Voltage with $1.1k\Omega$ series resistor from data bus to SMBDAT pin	I _{PULLUP} = 350μA			0.4	V
	SMBus Data Line Logic Low Voltage without series resistor from data bus to SMBDAT pin	I _{PULLUP} = 4mA			0.17	V
SMBus TIMING	SPECIFICATIONS					
f _{SMB}	SMBus Clock Frequency				250	kHz
t _{BUF}	Bus Free Time Between Stop and Start Condition		4.7			μs
[†] HD:STA	Hold Time After (Repeated) START Condition. After this Period, the First Clock is Generated		4.0			μs
t _{SU:STA}	Repeated Start Condition Setup Time		4.7			μs
t _{SU:STO}	Stop Condition Setup Time		4.0			μs
t _{HD: DAT}	Data Hold Time (Note 9)		300			ns
t _{SU:DAT}	Data Setup Time (Note 9)		250			ns
t _{LOW}	Clock Low Period		4.7			μs
tHIGH	Clock High Period		4.0			μs
t _F	Clock/Data Fall Time (Note 9)				300	ns
CURRENT SOUR	CES					
V _{HEADROOM}	Dominant Channel Current Source Headroom at CH Pin	$I_{LED} = 50\text{mA}$ $T_A = +25^{\circ}\text{C}$		1.0		V
V _{ISET}	Voltage at ISET Pin		1.18	1.21	1.24	V
ILEDmax Maximum LED Current per Channel		LED config = 8P10S with VF = 3.4V and V_{IN} = 11V		50		mA
PWM GENERATO	DR					
FPWM	Generated PWM Frequency	$R_{FPWM} = 330k\Omega$	180	200	220	Hz
		$R_{FPWM} = 3.3k\Omega$	18	20	22	kHz
Dimming Range	PWM Dimming Duty Cycle Limits (Note 9)	f _{PWM} ≤ 30kHz	0.4		100	%
VFSW	FSW Voltage	$R_{FSW} = 33k\Omega$	1.18	1.21	1.24	V
FPWMI	PWMI Input Frequency Range (Note 9)		200		20k	Hz
VFPWM	VFPWM Voltage	$R_{FPWM} = 3.3k\Omega$	1.18	1.21	1.25	V

NOTES:

- 7. Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested.
- 8. At maximum $V_{\mbox{\scriptsize IN}}$ of 26V, minimum $V_{\mbox{\scriptsize OUT}}$ is 28V. Minimum $V_{\mbox{\scriptsize OUT}}$ can be lower at lower $V_{\mbox{\scriptsize IN}}$
- 9. Limits established by characterization and are not production tested.

Typical Performance Curves

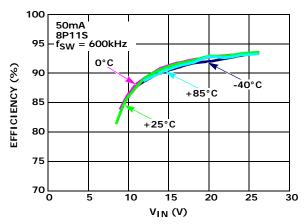


FIGURE 3. EFFICIENCY vs $V_{\mbox{\footnotesize{IN}}}$ vs TEMPERATURE AT 50mA

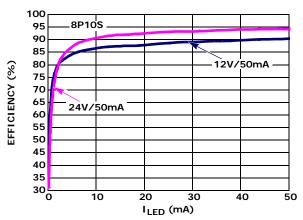


FIGURE 5. EFFICIENCY vs I_{LED}

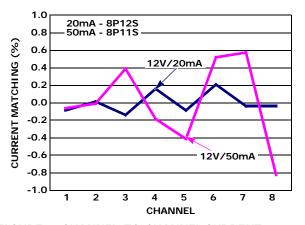


FIGURE 7. CHANNEL-TO-CHANNEL CURRENT MATCHING EXAMPLE

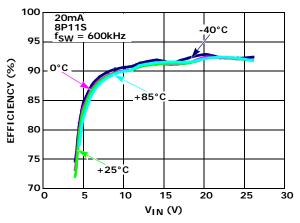


FIGURE 4. EFFICIENCY vs V_{IN} vs TEMPERATURE AT 20mA

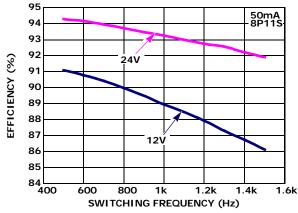


FIGURE 6. EFFICIENCY vs SWITCHING FREQUENCY

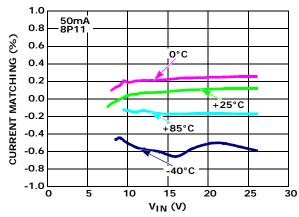


FIGURE 8. CURRENT MATCHING VS V_{IN} VS TEMPERATURE

Typical Performance Curves (Continued)

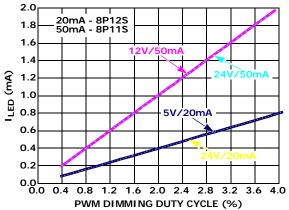


FIGURE 9. CURRENT LINEARITY vs LOW LEVEL PWM DIMMING DUTY CYCLE

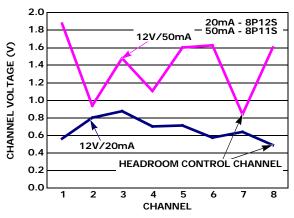


FIGURE 10. TYPICAL CHANNEL VOLTAGE EXAMPLE

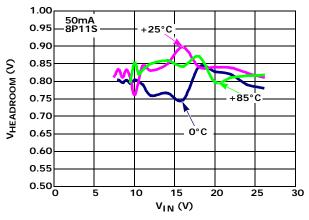


FIGURE 11. V_{HEADROOM} vs V_{IN} vs TEMPERATURE AT 50mA

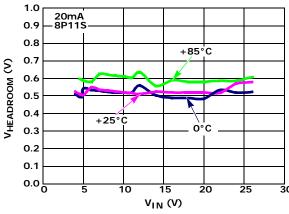


FIGURE 12. $V_{\mbox{\scriptsize HEADROOM}}$ vs $V_{\mbox{\scriptsize IN}}$ vs TEMPERATURE AT 20mA

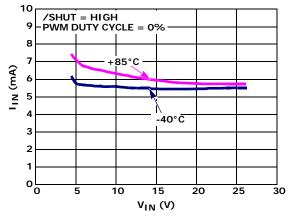


FIGURE 13. QUIESCENT CURRENT vs V_{IN} vs TEMPERATURE WITH /SHUT ENABLE

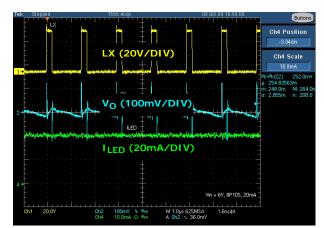


FIGURE 14. V_{OUT} RIPPLE VOLTAGE

Typical Performance Curves (Continued)

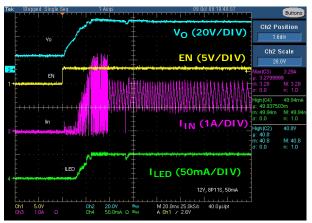


FIGURE 15. IN-RUSH CURRENT and LED CURRENT AT $V_{I\,N}=12V$

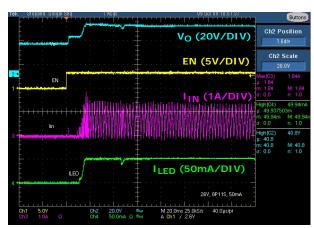


FIGURE 16. IN-RUSH CURRENT AND LED CURRENT AT $V_{1N} = 26V$

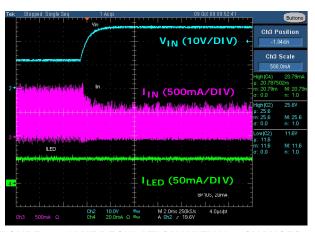


FIGURE 17. LINE REGULATION WITH V_{IN} CHANGES FROM 12V TO 26V DISABLE PROFILE

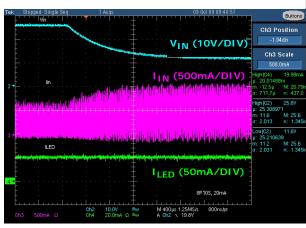


FIGURE 18. LINE REGULATION WITH $V_{\mbox{\scriptsize IN}}$ CHANGES FROM 26V TO 12V

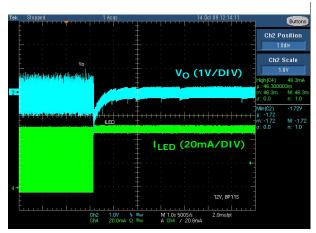


FIGURE 19. LOAD REGULATION WITH I_{LED} CHANGES FROM 0.4% TO 100% PWM DIMMING

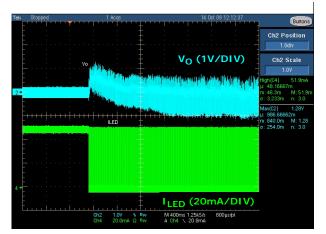


FIGURE 20. LOAD REGULATION WITH I $_{\rm LED}$ CHANGES FROM 100% TO 0.4% PWM DIMMING

Typical Performance Curves (Continued)



FIGURE 21. LOAD REGULATION WITH I_{LED} CHANGES FROM 0% TO 100% PWM DIMMING

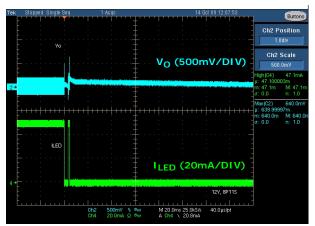


FIGURE 22. LOAD REGULATION WITH I_{LED} CHANGES FROM 100% to 0% PWM DIMMING

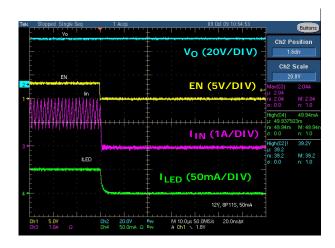


FIGURE 23. DISABLE PROFILE

Theory of Operation

PWM Boost Converter

The current mode PWM boost converter produces the minimal voltage needed to enable the LED string with the highest forward voltage drop to run at the programmed current. The ISL97677 employs current mode control boost architecture that has a fast current sense loop and a slow voltage feedback loop. Such architecture achieves a fast transient response that is essential for the notebook backlight application where the power can be several Li-ion cell batteries or instantly change to an AC/DC adapter without rendering a noticeable visual nuisance. The number of LEDs that can be driven by ISL97677 depends on the type of LED chosen in the application. The ISL97677 is capable of boosting up to 45V and drive 8 channels of LEDs at maximum of 45mA per channel.

Current Matching and Current Accuracy

Each channel of the LED current is regulated by the current source circuit, as shown in Figure 24.

The LED peak current is set by translating the R_{SET} current to the output with a scaling factor of 707.9/ R_{SET} . The source terminals of the current source MOSFETs are designed to run at 500mV to optimize power loss vs accuracy requirements. The sources of errors of the channel-to-channel current matching come from the op amps offset, internal layout, reference, and current source resistors. These parameters are optimized for current matching and absolute current accuracy. However, the absolute accuracy is additionally determined by the external R_{SET} . A 0.1% tolerance resistor is recommended.

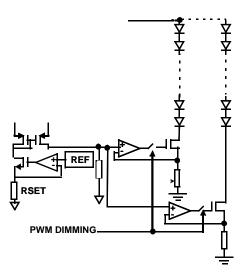


FIGURE 24. SIMPLIFIED CURRENT SOURCE CIRCUIT

Dynamic Headroom Control

The ISL97677 features a proprietary Dynamic Headroom Control circuit that detects the highest forward voltage string or effectively the lowest voltage from any of the CH pins. When this lowest I_{IN} voltage is lower than the short circuit threshold, V_{SC} , such voltage will be used as the feedback signal for the boost regulator. The boost makes the output to the correct level such that the lowest CH pin is at the target headroom voltage. Since all LED strings are connected to the same output voltage, the other CH pins will have a higher voltage, but the regulated current source circuit on each channel will ensure that each channel has the same programmed current. The output voltage will regulate cycle by cycle and is always referenced to the highest forward voltage string in the architecture.

OVP and VOUT Requirement

The Overvoltage Protection (OVP) pin has a function of setting the overvoltage trip level as well as limiting the V_{OUT} regulation range.

The ISL97677 OVP threshold is set by $R_{\mbox{UPPER}}$ and $R_{\mbox{LOWER}}$ as shown in Equation 1:

$$V_{OUT\ OVP} = 1.21V \times (R_{UPPER} + R_{LOWER}) / R_{LOWER}$$
 (EQ. 1)

 V_{OUT} can only regulate between 64% and 100% of the $V_{OUT-OVP}$ such that:

Allowable $V_{OUT} = 64\%$ to 100% of V_{OUT_OVP}

For example, if 10 LEDs are used with the worst case V_{OUT} of 35V. If R_1 and R_2 are chosen such that the OVP level is set at 40V, then the V_{OUT} is allowed to operate between 25.6V and 40V. If the requirement is changed to a 6 LEDs 21V V_{OUT} application, then the OVP level must be reduced and users should follow $V_{OUT} = (64\% \sim 100\%)$ OVP requirement. Otherwise, the headroom control will be disturbed such that the channel voltage can be much higher than expected and sometimes it can prevents the driver from operating properly.

The ratio of the OVP capacitors should be the inverse of the OVP resistors. For example, if $R_{UPPER}/R_{LOWER} = 33/1$, then $C_{UPPER}/C_{LOWER} = 1/33$ with $C_{UPPER} = 100$ pF and $C_{LOWER} = 3.3$ nF.

Dimming Controls

The ISL97677 allows two ways of controlling the LED current, and therefore, the brightness. They are:

- 1. DC current adjustment
- 2. PWM chopping of the LED current defined in Step 1. There are various ways to achieve DC or PWM current control, which will be described in the following.

In any dimming controls, the EN pin must be high. EN is a high voltage pin that can be applied with a digital signal or tied directly to $V_{\mbox{\footnotesize{IN}}}$ for enable function.

MAXIMUM DC CURRENT SETTING

The initial brightness should be set by choosing an appropriate value for R_{SET} . This should be chosen to fix the maximum possible LED current:

$$I_{LEDmax} = \frac{707.9}{R_{SET}}$$
 (EQ. 2)

Alternatively, the R_{SET} can be replaced by digital potentiometer for adjustable current. On the other hand, the current accuracy is designed when RSET is set at 20m to 40mA.

PWM CONTROL

The ISL97677 also provides PWM dimming by PWM chopping of the current in the LEDs for all 8 channels to provide an average LED current. During the On periods, the LED current will be defined by the value of R_{SET} , as described in Equation 1.

PWM Dimming Frequency Adjustment

The dimming frequencies of all modes are set by an external resistor at the FPWM pin as shown in Equation 3:

$$f_{PWM} = \frac{6.66 \times 10^7}{RPWM} \tag{EQ. 3}$$

where f_{PWM} is the desirable PWM dimming frequency and R_{FPWM} is the setting resistor.

External PWM Dimming

The ISL97677 can operate as basic PWM dimming LED driver with or without the need of SMBus/I 2 C interface. To do so, users need to set EN = high and SMBCLK/SCL = grounded or floating, SMBDAT/SDA = grounded or floating. The EN is a high voltage pin that can be applied with a digital I/O signal or tie to V_{IN}. The PWM output will follow the PWM input and the dimming frequency will be set by R_{PWM}.

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Switching Frequency

The boost switching frequency can be adjusted by a resistor as shown in Equation 4:

$$f_{SW} = \frac{(5 \times 10^{10})}{R_{OSC}}$$
 (EQ. 4)

where f_{SW} is the desirable boost switching frequency and R_{OSC} is the setting resistor.

5V and 2.3V Low Dropout Regulators

A 5V LDO regulator is present at the VDC pin to develop the necessary low voltage supply, which is used by the chips internal control circuitry. Because VDC is an LDO pin, it requires a bypass capacitor of $1\mu F$ or more for the regulation. The VDC pin can be used for a coarse regulator or reference but do not pull more than few mA from it.

Similarly, a 2.3V LDO regulator is present at the VLOGIC pin to develop the necessary low voltage supply for the chip's internal logic control circuitry. A $1\mu F$ bypass capacitor or more is needed for regulation. The VLOGIC pin can be used as a coarse regulator or reference but do not pull more than few mA from it.

Soft-Start

The ISL97677 uses a digital soft-start where the boost current limit is stepped up in 8 steps. The initial current limit level is set to one ninth of the full current limit, with subsequent steps increasing this by a ninth every 2ms. In the event that no LEDs have been conducting during the interval since the last step (for example, if the LEDs are running at low duty cycle at low PWM frequency) then the step will be delayed until the LEDs are conducting. If the LEDs are disabled and re-enabled again then soft start will be restarted when the LEDs are enabled.

Fault Protection and Monitoring

The ISL97677 features extensive protection functions to cover all the perceivable failure conditions. The failure mode of a LED can be either open circuit or as a short. The behavior of an open circuited LED can additionally take the form of either infinite resistance or, for some LEDs, a zener diode, which is integrated into the device in parallel with the now opened LED.

For basic LEDs (which do not have built-in zener diodes), an open circuit failure of an LED will only result in the loss of one channel of LEDs without affecting other channels. Similarly, a short circuit condition on a channel that results in that channel being turned off does not affect other channels unless a similar fault is occurring. All LED faults are reported via the SMBus interface to Register 0x02 (Fault/Status register).

Due to the lag in boost response to any load change at its output, certain transient events (such as significant step changes in LED duty cycle) can transiently look like LED fault modes. The ISL97677 uses feedback from the LEDs to determine when it is in a stable operating region and

prevents apparent faults during these transient events from allowing any of the LED strings to fault out. See Table 1 for more details.

Short Circuit Protection (SCP)

The short circuit detection circuit monitors the voltage on each channel and disables faulty channels which are detected above the programmed short circuit threshold. There are three selectable levels of short circuit threshold (3V, 4V, and 5V) that can be programmed through the Configuration Register 0x0F. When an LED becomes shorted, the action taken is described in Table 1. The default short circuit threshold is 4V. The detection of this failure mode can be disabled by SMBus interface via Register 0x0F.

Open Circuit Protection (OCP)

When one of the LEDs becomes open circuit, it can behave as either an infinite resistance or a gradually increasing finite resistance. The ISL97677 monitors the current in each channel such that any string which reaches the intended output current is considered "good". Should the current subsequently fall below the target, the channel will be considered an "open circuit". Furthermore, should the boost output of the ISL97677 reach the OVP limit or should the lower over-temperature threshold be reached, all channels which are not "good" will immediately be considered as "open circuit". Detection of an "open circuit" channel will result in a time-out before disabling of the affected channel.

Some users employ some special types of LEDs that have zener diode structure in parallel with the LED for ESD enhancement, thus enabling open circuit operation. When this type of LED goes open circuit, the effect is as if the LED forward voltage has increased, but no light will be emitted. Any affected string will not be disabled, unless the failure results in the boost OVP limit being reached, allowing all other LEDs in the string to remain functional. Care should be taken in this case that the boost OVP limit and SCP limit are set properly, so as to make sure that multiple failures on one string do not cause all other good channels to be faulted out. This is due to the increased forward voltage of the faulty channel making all other channel look as if they have LED shorts. See Table 1 for details for responses to fault conditions.

Overvoltage Protection (OVP)

The integrated OVP circuit monitors the output voltage and keeps the voltage at a safe level. The OVP threshold is set as shown in Equation 5:

$$OVP = 1.21V \times (R_{IJPPER} + R_{IOWER}) / R_{IOWER}$$
 (EQ. 5)

These resistors should be large to minimize the power loss. For example, a 1Mk Ω RUPPER and 30k Ω RLOWER sets OVP to 41.2V. Large OVP resistors also allow COUT discharges slowly during the PWM Off time. Parallel capacitors should be placed across the OVP resistors such that RUPPER/RLOWER = CLOWER/CUPPER. Using a CUPPER value of at least 30pF is recommended. These

capacitors reduce the AC impedance of the OVP node, which is important when using high value resistors.

Undervoltage Lockout

If the input voltage falls below the UVLO level of 2.8V, the device will stop switching and be reset. Operation will restart only if the device control interface re-enables it once the input voltage is back in the normal operating range. Also all digital settings will be reset to their default states.

Over-Temperature Protection (OTP)

The ISL97677 includes two over-temperature thresholds. The lower threshold is set to +130°C. When this threshold is reached, any channel which is outputting current at a level significantly below the regulation target will be treated as "open circuit" and disabled after a time-out period. The intention of the lower threshold is to allow bad channels to be isolated and disabled before they cause enough power dissipation (as a result of other channels having large voltages across them) to hit the upper temperature threshold.

The upper threshold is set to +150°C. Each time this is reached, the boost will stop switching and the output current sources will be switched off and stay off until the control interface disables and re-enables it. Hitting of the

upper threshold will also set the thermal fault bit of the Fault/Status register 0x02. Unless disabled via the /SHUT pin, the device stays in an active state throughout, allowing the external processor to interrogate the fault condition.

For the extensive fault protection conditions, please refer to Figure 25 and Table 1 for details.

Shutdown

When the EN pin is low the entire chip is shut down to give close to zero shutdown current. The digital interfaces will not be active during this time.

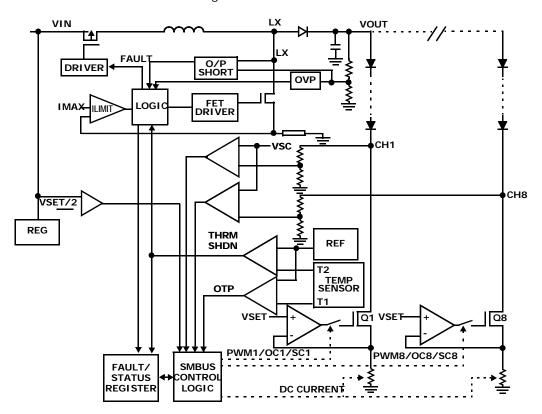
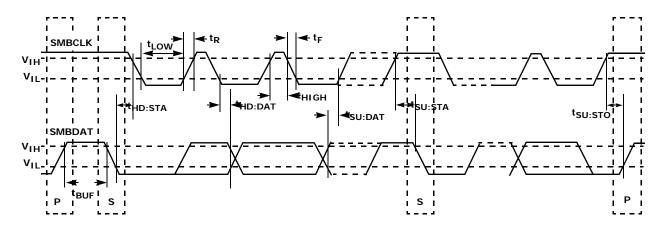


FIGURE 25. SIMPLIFIED FAULT PROTECTIONS

ISL97677

TABLE 1. PROTECTIONS TABLE

CASE	FAILURE MODE	DETECTION MODE	FAILED CHANNEL ACTION	GOOD CHANNELS ACTION	V _{OUT} REGULATED BY
1	CH1 Short Circuit	Upper Over-Temperature Protection limit (OTP) not triggered and VI _{INO} < VSC	CH1 ON and burns power	CH2 through CH8 Normal	Highest VF of CH2 through CH8
2	CH1 Short Circuit	Upper OTP triggered but V _{IN1} < VSC	CH1 goes off	Same as CH1	Highest VF of CH2 through CH8
3	CH1 Short Circuit	Upper OTP not triggered but VI _{IN1} > VSC	CH1 disabled after 6 PWM cycles time-out.	If 3 channels are already shut down, all channels will be shut down. Otherwise CH2-8 will remain as normal	Highest VF of CH2 through CH8
4	CH1 Open Circuit with infinite resistance	Upper OTP not triggered and VIIN1 < VSC	V _{OUT} will ramp to OVP. CH1 will time-out after 6 PWM cycles and switch off. V _{OUT} will drop to normal level.	time-out after 6 PWM cycles and switch off. V _{OUT} will drop	
5	CH1 LED Open Circuit but has paralleled Zener	Upper OTP not triggered and VI _{IN1} < VSC	CH1 remains ON and has highest VF, thus V _{OUT} increases	CH2 through CH8 ON, Q2 through Q8 burn power	VF of CH1
6	CH1 LED Open Circuit but has paralleled Zener	Upper OTP triggered but VI _{IN1} < VSC	CH1 goes off	Same as CH1	VF of CH1
7	CH1 LED Open Circuit but has paralleled Zener	Upper OTP not triggered but VIIN1 > VSC	CH1 OFF	CH2 through CH8 Normal	Highest VF of CH2 through CH8
		Upper OTP not triggered but VIINx > VSC	CH1 remains ON and has highest VF, thus V _{OUT} increases.	V _{OUT} increases then CH-X switches OFF. This is an unwanted shut off and can be prevented by setting OVP and/or VSC at an appropriate level.	VF of CH1
8	Channel-to- Channel ΔVF too high	Lower OTP triggered but VIINx < VSC	Any channel at below the target current will fault out after 6 PWM cycles. Remaining channels driven with normal current.		Highest VF of CH1 through CH8
9	Channel-to- Channel ΔVF too high	Upper OTP triggered but VIINx < VSC	All channels switched off		Highest VF of CH1 through CH8
10	Output LED string voltage too high	V _{OUT} > VOVP	Driven with normal current. An target current will time-out after	Highest VF of CH1 through CH8	
11	V _{OUT} /LX shorted to GND		LX will not switch		



NOTES:

SMBus Description

S = Start condition

P = Stop condition

A = Acknowledge

 \overline{A} = Not acknowledge

 R/\overline{W} = Read enable at high; Write enable at low

FIGURE 26. SMBUS INTERFACE

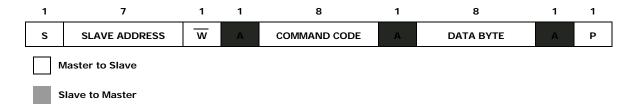
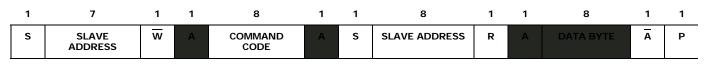


FIGURE 27. WRITE BYTE PROTOCOL



Master to Slave

Slave to Master

FIGURE 28. READ BYTE PROTOCOL

Write Byte

The Write Byte protocol is only three bytes long. The first byte starts with the slave address followed by the "command code," which translates to the "register index" being written. The third byte contains the data byte that must be written into the register selected by the "command code". A shaded label is used on cycles during which the slaved backlight controller "owns" or "drives" the Data line. All other cycles are driven by the "host master."

Read Byte

As shown in the Figure 28, the four byte long Read Byte protocol starts out with the slave address followed by the "command code" which translates to the "register index." Subsequently, the bus direction turns around with the rebroadcast of the slave address with bit 0 indicating a read ("R") cycle. The fourth byte contains the data being returned by the backlight controller. That byte value in the data byte reflects the value of the register being queried at the "command code" index. Note the bus directions, which are highlighted by the shaded label that is used on cycles during which the slaved backlight controller "owns" or "drives" the Data line. All other cycles are driven by the "host master."

Slave Device Address

The slave address contains 7 MSB plus one LSB as R/W bit, but these 8 bits are usually called Slave Address bytes. As shown in Figure 29, the high nibble of the slave address byte is 0x5 or 0101b to denote the "backlight controller class." Bit 3 in the lower nibble of the slave address byte is 1. Bit 0 is always the R/W bit, as specified by the SMBus protocol. Note: In this document, the device address will always be expressed as a full 8-bit address instead of the shorter 7-bit address typically used in other backlight controller specifications to avoid

confusion. Therefore, if the device is in the write mode where bit 0 is 0, the slave address byte is 0x58 or 01011000b. If the device is in the read mode where bit 0 is 1, the slave address byte is 0x59 or 01011001b.

The backlight controller may sense the state of the pins at POR or during normal operation—the pins will not change state while the device is in operation.

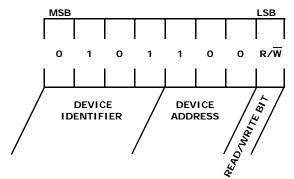


FIGURE 29. SLAVE ADDRESS BYTE DEFINITION

SMBus Register Definitions

The backlight controller registers are Byte wide and accessible via the SMBus Read/Write Byte protocols. Their bit assignments are provided in the following sections with reserved bits containing a default value of "0".

TABLE 2A. REGISTER LISTING

ADDRESS	REGISTER	BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0	DEFAULT VALUE	SMBUS PROTOCOL
0x00	PWM Brightness Control Register	BRT7	BRT6	BRT5	BRT4	BRT3	BRT2	BRT1	BRT0	0xFF	Read and Write
0x01	Device Control Register	Reserved	Reserved	Reserved	Reserved	Reserved	PWM_MD	PWM_SEL	BL_CTL	0x00	Read and Write
0x02	Fault/Status Register	Reserved	Reserved	2_CH_SD	1_CH_S D	BL_STAT	OV_CURR	THRM_SHDN	FAULT	0x00	Read Only
0x03	Identification Register	LED PANEL	MFG3	MFG2	MFG1	MFG0	REV2	REV1	REV0	0xC8	Read Only

TABLE 2B. DATA BIT DESCRIPTIONS

ADDRESS	REGISTER	DATA BIT DESCRIPTIONS						
0x00	PWM Brightness Control Register	BRT[70] = 2	BRT[70] = 256 steps of DPWM duty cycle brightness control					
0x01	Device Control Register	PWM_MD = PWM mode select bit (1 = absolute brightness, 0 = % change), default = 0 PWM_SEL = Brightness control select bit (1 = control by PWMI, 0 = control by SMBus), default = 0 BL_CTL = BL On/Off (1 = On, 0 = Off), default = 0						
			PWM_MD	PWM_SEL	MODE			
			Х	1	PWMI Mode			
			1	0	SMBus Mode			
			0	0	SMBus and PWMI mode with DPST			
0x02	Fault/Status Register	2_CH_SD = Two LED output channels are shutdown (1 = shutdown, 0 = OK) 1_CH_SD = One LED output channel is shutdown (1 = shutdown, 0 = OK) BL_STAT = BL status (1 = BL On, 0 = BL Off) OV_CURR = Input overcurrent (1 = Overcurrent condition, 0 = Current OK) THRM_SHDN = Thermal Shutdown (1 = Thermal fault, 0 = Thermal OK) FAULT = Fault occurred (Logic "OR" of all of the fault conditions)						
0x03	Identification Register				ndors available. Intersil is vendor IC ph Rev 7 allowed for silicon spins)	9)		

PWM Brightness Control Register (0x00)

The Brightness control resolution has 256 steps of PWM duty cycle adjustment. The bit assignment is shown in Tables 2A and 2B. All of the bits in this Brightness Control Register can be read or write. Step 0 corresponds to the minimum step where the current is less than $10\mu A.$ Steps 1 to 255 represent the linear steps between 0.39% and 100% duty cycle with approximately 0.39% duty cycle adjustment per step.

- An SMBus Write Byte cycle to Register 0x00 sets the PWM brightness level only if the backlight controller is in SMBus mode (see Table 3 "Operating Modes selected by Device Control Register Bits 1 and 2").
- An SMBus Read Byte cycle to Register 0x00 returns the programmed PWM brightness level, regardless of the value of PWM SEL.
- An SMBus setting of 0xFF for Register 0x00 sets the backlight controller to the maximum brightness.
- An SMBus setting of 0x00 for Register 0x00 sets the backlight controller to the minimum brightness output in which the LED current is guaranteed to be less than 10µA.
- Default value for Register 0x00 is 0xFF.

Device Control Register (0x01)

This register has 2 bits that control the operating mode of the backlight controller and a single bit that controls the BL ON/OFF state. The remaining bits are reserved. The bit assignment is shown in Tables 2A and 2B. All other bits in the Device Control Register will read as low

unless otherwise written. Bits 7 and 6 are not implemented and will always read low.

TABLE 3. OPERATING MODES SELECTED BY DEVICE CONTROL REGISTER BITS 1 AND 2

PWM_MD	PWM_SEL	MODE
Х	1	PWMI Mode
1	0	SMBus Mode
0	0	SMBus and PWMI Mode with DPST

The PWM_SEL bit determines whether the SMBus or PWMI input should drive the output brightness in terms of PWM dimming. When PWM_SEL bit is 1, the PWMI drives the output brightness regardless of what the PWM_MD is.

When the PWM_SEL bit is 0, the PWM_MD bit selects the manner in which the PWM dimming is to be interpreted; when this bit is 1, the PWM dimming is based on the SMBus brightness setting. When this bit is 0, the PWM dimming reflects a percentage change in the current brightness programmed in the SMBus Register 0x00, i.e. DPST (Display Power Saving Technology) mode, as shown in Equation 6:

DPST Brightness =
$$Cbt \times PWMI$$
 (EQ. 6)

Where:

Cbt = Current brightness setting from SMBus Register 0x00 without influence from the PWMI

PWMI = is the percent duty cycle of the PWMI

For example, the Cbt = 50% duty cycle programmed in the SMBus Register 0x00 and the PWM frequency is tuned to be 200Hz with an appropriate capacitor at the FPWM pin. On the other hand, PWMI is fed with a 1kHz 30% high PWM signal. When PWM_SEL = 0 and PWM_MD = 0, the device is in DPST operation where DPST brightness = 15% PWM dimming at 200Hz.

- · All reserved bits return a "0" when read.
- All reserved bits have no functional effect when written.
- All defined control bits return their current, latched value when read.
- A value of 1 written to BL_CTL turns on the BL in 4ms or less after the write cycle completes. The BL is deemed to be on when Bit 3 BL_STAT of Register 0x02 is 1 and Register 0x09 is not 0. See Tables 2A and 2B.
- A value of 0 written to BL_CTL immediately turns off the BL. The BL is deemed to be off when Bit 3 BL_STAT of Register 0x02 is 0 and Register 0x09 is 0. See Tables 2A and 2B.
- **Note that the behavior of Register 0x00
 (Brightness Control Register) is affected by certain combinations of the control bits, as shown in Table 3
 "Operating Modes Selected by Device Control Register Bits 1 and 2."
- When an SMBus mode is selected, Register 0x00 reflects the last value written to it. But, when any non-SMBus mode is selected, Register 0x00 reflects the current brightness value based on the current mode of operation, with the exception of SMBus mode with DPST, where PWM_MD = 0 and PWM_SEL = 0.
- When SMBus mode with DPST is selected, Register 0x00 reflects the last value written to it from SMBus.
- When a write to Register 0x01 (Device Control Register) causes the backlight controller to transition to an SMBus mode, the brightness of the BL does not change. On the other hand, when a write to Register 0x01causes the backlight controller to transition to a non-SMBus mode, the brightness of the BL changes as appropriate for the new mode.
- The default value for Register 0x01 is 0x00.

Fault/Status Register (0x02)

This register has 6 status bits that allow monitoring of the backlight controller's operating state. Bit 0 is a logical "OR" of all fault codes to simplify error detection. Not all of the bits in this register are fault related (Bit 3 is a simple BL status indicator). The remaining bits are reserved and return a "0" when read and ignore the bit value when written. All of the bits in this register are

read-only, with the exception of bit 0, which can be cleared by writing to it.

- A Read Byte cycle to Register 0x02 indicates the current BL on/off status in BL_STAT (1 if the BL is on, 0 if the BL is off).
- A Read Byte cycles to Register 0x2 also returns FAULT as the logical OR of THRM_SHDN, OV_CURR, 2_CH_SD, and 1_CH_SD should these events occur.
- 1_CH_SD returns a 1 if one or more channels have faulted out.
- 2_CH_SD returns a 1 if two or more channels have faulted out.
- A fault will not be reported in the event that the BL is commanded on and then immediately off by the system.
- When FAULT is set to 1, it will remain at 1 even if the signal which sets it goes away. FAULT will be cleared when the BL_CTL bit of the Device Control Register is toggled or when written low. At that time, if the fault condition is still present or reoccurs, FAULT will be set to 1 again. BL_STAT will not cause FAULT to be set.
- The controller will not indicate a fault if the VBL+ goes away, whether or not the LEDs were on at the time of the power loss. This can occur if there is some hang condition that causes the user to force the system off by holding the power button down for 4s.
- The default value for Register 0x02 is 0x00.

Identification Register (0x03)

The ID register contains 3-bit fields to denote the LED driver (always set to 1), manufacturer and the silicon revision of the controller IC. The bit field widths allow up to 16 vendors with up to 8 silicon revisions each. In order to keep the number of silicon revisions low, the revision field will not be updated unless the part will make it out to the user's factory. Thus, if during the engineering development process, 3 silicon spins were needed, the next available revision ID would be used for all 3 spins until that same ID made it to the factory. Except Bit 7, which has to be 1, all of the bits in this register are read-only.

- Vendor ID 9 represents Intersil Corporation.
- The default value for Register 0x03 is 0xC8.

The initial value of REV shall be 0. Subsequent values of REV will increment by 1.

Components Selections

According to the inductor Voltage-Second Balance principle, the change of inductor current during the switching regulator On-time is equal to the change of inductor current during the switching regulator Off-time.

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Since the voltage across an inductor is as shown in Equation 7:

$$V_{1} = L \times \Delta I_{1} / \Delta t \tag{EQ. 7}$$

and ΔI_{\perp} @ On = ΔI_{\perp} @ Off, therefore:

$$(V_1 - 0)/L \times D \times t_S = (V_0 - V_D - V_I)/L \times (1 - D) \times t_S$$
 (EQ. 8)

where D is the switching duty cycle defined by the turn-on time over the switching periods. V_D is Schottky diode forward voltage that can be neglected for approximation.

Rearranging the terms without accounting for V_D gives the boost ratio and duty cycle respectively as Equations 9 and 10:

$$V_0/V_1 = 1/(1-D)$$
 (EQ. 9)

$$D = (V_{O} - V_{I})/V_{O}$$
 (EQ. 10)

Input Capacitor

Switching regulators require input capacitors to deliver peak charging current and to reduce the impedance of the input supply. This reduces interaction between the regulator and input supply, thereby improving system stability. The high switching frequency of the loop causes almost all ripple current to flow in the input capacitor, which must be rated accordingly.

A capacitor with low internal series resistance should be chosen to minimize heating effects and improve system efficiency, such as X5R or X7R ceramic capacitors, which offer small size and a lower value of temperature and voltage coefficient compared to other ceramic capacitors.

It is recommended that an input capacitor of at least $10\mu\text{F}$ be used. Ensure the voltage rating of the input capacitor is suitable to handle the full supply range.

Inductor

The selection of the inductor should be based on its maximum and saturation current (I_{SAT}) characteristics, power dissipation (DCR), EMI susceptibility (shielded vs unshielded), and size. Inductor type and value influence many key parameters, including ripple current, current limit, efficiency, transient performance and stability.

The inductor's maximum current capability must be adequate enough to handle the peak current at the worst case condition. Additionally if an inductor core is chosen with too low a current rating, saturation in the core will cause the effective inductor value to fall, leading to an increase in peak to average current level, poor efficiency and overheating in the core. The series resistance, DCR, within the inductor causes conduction loss and heat dissipation. A shielded inductor is usually more suitable for EMI susceptible applications, such as LED backlighting.

The peak current can be derived from the voltage across the inductor during the Off-period, as expressed in Equation 11:

$$IL_{peak} = (V_{O} \times I_{O})/(85\% \times V_{I}) + 1/2[V_{I} \times (V_{O} - V_{I})/(L \times V_{O} \times f_{SW})$$
(EQ. 11)

The choice of 85% is just an average term for the efficiency approximation. The first term is the average current, which is inversely proportional to the input voltage. The second term is the inductor current change, which is inversely proportional to L and f_{SW} . As a result, for a given switching.

	PWM BRIGHTNESS CONTROL
REGISTER 0x00	REGISTER

BRT7 BRT6 BRT5 BRT4 BI	RT3 BRT2 BRT1 BRT0
------------------------	--------------------

Bit 7 (R/W) Bit 6 (R/W) Bit 5 (R/W) Bit 4 (R/W) Bit 3 (R/W) Bit 2 (R/W) Bit 1 (R/W) Bit 0 (R/W)

BIT ASSIGNMENT	BIT FIELD DEFINITIONS
BRT[70]	= 256 steps of PWM brightness levels

FIGURE 30. DESCRIPTIONS OF BRIGHTNESS CONTROL REGISTER

REGISTER 0x01	DEVICE CONTROL REGISTER

RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	PWM_MD	PWM_SEL	BL_CTL
Bit 7 (R/W)	Bit 6 (R/W)	Bit 5 (R/W)	Bit 4 (R/W)	Bit 3 (R/W)	Bit 2 (R/W)	Bit 1 (R/W)	Bit 0 (R/W)

BIT ASSIGNMENT	BIT FIELD DEFINITIONS
PWM_MD	= PWM mode select bit (1 = absolute brightness, 0 = % change) default = 0
PWM_SEL	= Brightness control select bit (1 = control by PWMI, 0 = control by SMBus) default = 0
BL_CTL	= BL On/Off (1 = On, 0 = Off) default = 0

FIGURE 31. DESCRIPTIONS OF DEVICE CONTROL REGISTER

REGISTER 0x02	FAULT/STATUS REGISTER
---------------	-----------------------

RESERVED	RESERVED	2_CH_SD	1_CH_SD	BL_STAT	OV_CURR	THRM_SHDN	FAULT
Bit 7 (R)	Bit 6 (R)	Bit 5 (R)	Bit 4 (R)	Bit 3 (R)	Bit 2 (R)	Bit 1 (R)	Bit 0 (R)

ВІТ	BIT ASSIGNMENT	BIT FIELD DEFINITIONS
Bit 5	2_CH_SD	= Two LED output channels are shutdown (1 = shutdown, 0 = OK)
Bit 4	1_CH_SD	= One LED output channel is shutdown (1 = shutdown, 0 = OK)
Bit 3	BL_STAT	= BL Status (1 = BL On, 0 = BL Off)
Bit 2	OV_CURR	= Input Overcurrent (1 = Overcurrent condition, 0 = Current OK)
Bit 1	THRM_SHDN	= Thermal Shutdown (1 = Thermal Fault, 0 = Thermal OK)
Bit 0	FAULT	= Fault occurred (Logic "OR" of all of the fault conditions)

FIGURE 32. DESCRIPTIONS OF FAULT/STATUS REGISTER

REGISTER 0x03	ID REGISTER
---------------	-------------

LED PANEL	MFG3	MFG2	MFG1	MFGO	REV2	REV1	REVO
Bit 7 = 1	Bit 6 (R)	Bit 5 (R)	Bit 4 (R)	Bit 3 (R)	Bit 2 (R)	Bit 1 (R)	Bit 0 (R)

BIT ASSIGNMENT	BIT FIELD DEFINITIONS
MFG[30]	= Manufacturer ID. See "Identification Register (0x03)" on page 19. Data 0 to 8 in decimal correspond to other vendors data 9 in decimal represents Intersil ID data 10 to 14 in decimal are reserved data 15 in decimal Manufacturer ID is not implemented
REV[20]	= Silicon rev (Rev 0 through Rev 7 allowed for silicon spins)

FIGURE 33. DESCRIPTIONS OF ID REGISTER

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Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest Rev.

DATE	REVISION	CHANGE
11/13/09	FN6996.1	Changed in OVP and VOUT Requirement Changed from: VOUT can only regulate between 61% and 100% of the VOUT_OVP such that: To: VOUT can only regulate between 64% and 100% of the VOUT_OVP such that From: Allowable VOUT = 61% to 100% of VOUT_OVP To: Allowable VOUT = 64% to 100% of VOUT_OVP From:then the VOUT is allowed to operate between 24.4V and 40V. To:then the VOUT is allowed to operate between 25.6V and 40V. From:should follow VOUT = (61% ~100%)OVP requirement To:should follow VOUT = (64% ~100%)OVP requirement. Changed VSC spec from "2.5Vmin, 3.4Vmax, 3.3min, 4.4max, 4.2min, 5.4max to "2.4Vmin, 3.6Vmax, 3.3min, 4.6max, 4.2min, 5.6max".
10/21/09	FN6996.0	Initial Release.

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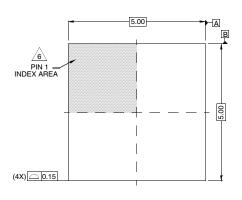
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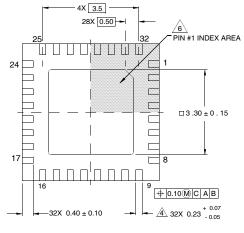
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Package Outline Drawing

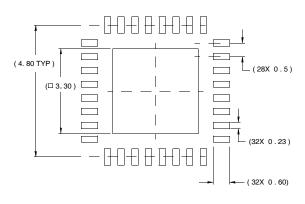
L32.5x5B 32 LEAD QUAD FLAT NO-LEAD PLASTIC PACKAGE Rev 2, 11/07



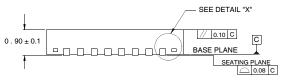
TOP VIEW



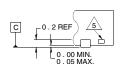
BOTTOM VIEW



TYPICAL RECOMMENDED LAND PATTERN



SIDE VIEW



DETAIL "X"

NOTES:

- Dimensions are in millimeters.
 Dimensions in () for Reference Only.
- 2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.
- 3. Unless otherwise specified, tolerance : Decimal ± 0.05
- 4. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
- 5. Tiebar shown (if present) is a non-functional feature.
- The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.



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